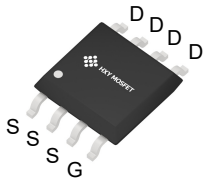
Description

The DMP3056LSS uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a Battery protection or in other Switching application.

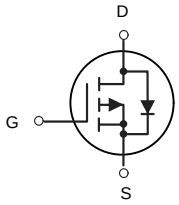


SOP-8

General Features

V_{DS} =-30V I_D =-9A

$R_{DS(ON)}$ < 20mΩ @ V_{GS}=10V



P-Channel MOSFET

Application

Battery protection

Load switch

Uninterruptible power supply

Package Marking and Ordering Information

Product ID	Pack	Brand	Qty(PCS)
DMP3056LSS	SOP-8	HXY MOSFET	3000

Absolute Maximum Ratings (T_C=25 C unless otherwise noted)

Symbol	Parameter	Rating	Units
V_{DS}	Drain-Source Voltage	- 30	V
VGS	Gate-Source Voltage	± 20	V
I_D@T_A=25℃	Drain Current[3], V_{GS} @ 10V	-9	A
I_D@T_A=70℃	Drain Current[3], V_{GS} @ 10V	-7.3	A
IDM	Pulsed Drain Current[1]	-50	A
P_D@T_A=25℃	Total Power Dissipation	2.5	W
	Linear Derating Factor	0.02	W/℃
TSTG	Storage Temperature Range	-55 to 150	℃
T_J	Operating Junction Temperature Range	-55 to 150	℃
Rthj-a	Maximum Thermal Resistance, Junction-ambient[3]	50	℃/W

Electrical Characteristics @Tj=25°C(unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
BV_{DSS}	Drain-Source Breakdown Voltage	V_{GS}=0V, I_D=-250uA	-30	-	-	V
RDS(ON)	Static Drain-Source On-Resistance[2]	V_{GS}=-10V, I_D=-7A	-	18	20	mΩ
		V_{GS}=-4.5V, I_D=-5A	-	32	36	mΩ
VGS(th)	Gate Threshold Voltage	V_{DS}=V_{GS}, I_D=-250uA	-1	-	-3	V
g_{fs}	Forward Transconductance	V_{DS}=-10V, I_D=-7A	-	16	-	S
IDSS	Drain-Source Leakage Current	V_{DS}=-24V, V_{GS}=0V	-	-	-30	uA
IGSS	Gate-Source Leakage	V_{GS}=±20V, V_{DS}=0V	-	-	±100	nA
Q_g	Total Gate Charge	I_D=-7A	-	18	29	nC
Q_{gs}	Gate-Source Charge	V_{DS}=-24V	-	3	-	nC
Q_{gd}	Gate-Drain ("Miller") Charge	V_{GS}=-4.5V	-	10	-	nC
td(on)	Turn-on Delay Time	V_{DS}=-15V	-	8	-	ns
t_r	Rise Time	I_D=-1A	-	6.6	-	ns
td(off)	Turn-off Delay Time	R_G=3.3Ω	-	44	-	ns
t_f	Fall Time	V_{GS}=-10V	-	34	-	ns
C_{iss}	Input Capacitance	V_{GS}=0V	-	1175	1690	pF
C_{oss}	Output Capacitance	V_{DS}=-25V	-	195	-	pF
C_{rss}	Reverse Transfer Capacitance	f=1.0MHz	-	190	-	pF
V_{SD}	Forward On Voltage[2]	I_S=-2.1A, V_{GS}=0V	-	-	-1.2	V
trr	Reverse Recovery Time	I_S=-7A, V_{GS}=0V, dI/dt=100A/μs	-	28	-	ns
Q_{rr}	Reverse Recovery Charge		-	18	-	nC

Notes:

1.Pulse width limited by Max. junction temperature.

2.Pulse test

3.Surface mounted on 1 in^2 copper pad of FR4 board, t ≤10sec ; 125 ℃/W when mounted on Min. cop

Typical Electrical and Thermal Characteristics (Curves)

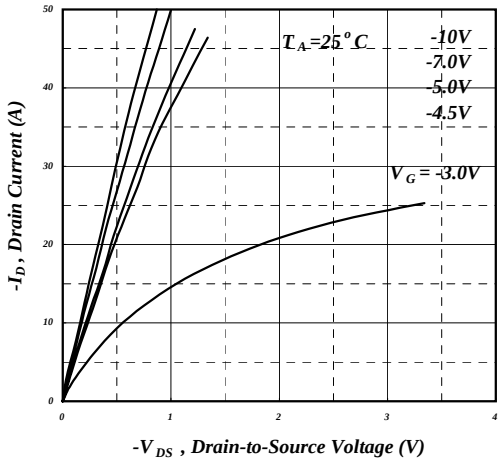


Fig 1. Typical Output Characteristics

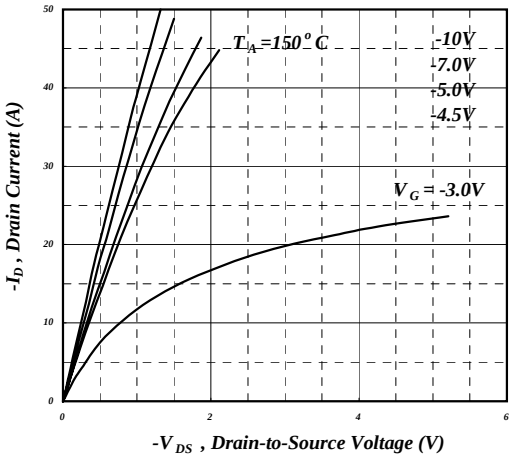


Fig 2. Typical Output Characteristics

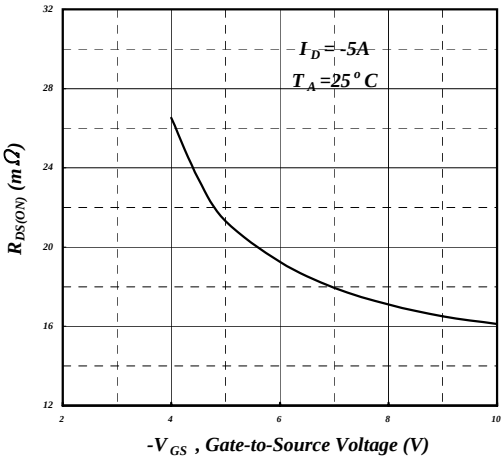


Fig 3. On-Resistance v.s. Gate Voltage

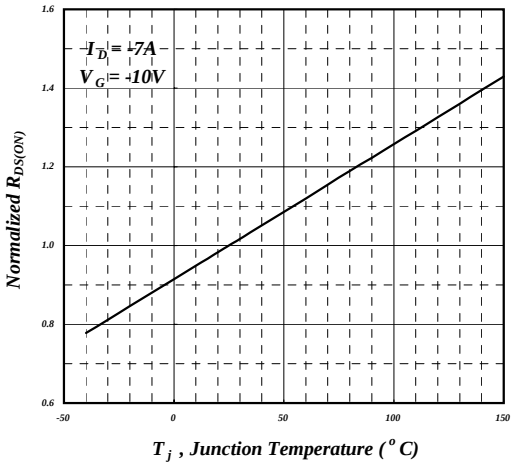


Fig 4. Normalized On-Resistance v.s. Junction Temperature

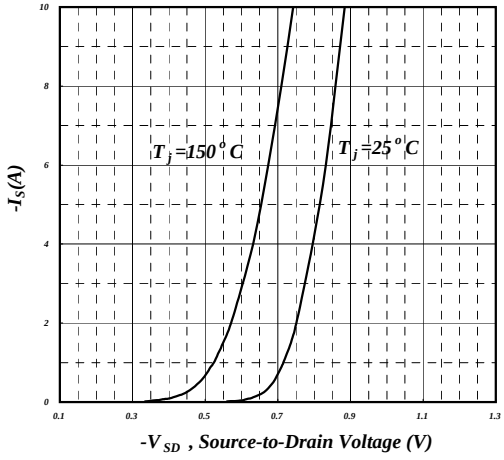


Fig 5. Forward Characteristic of Reverse Diode

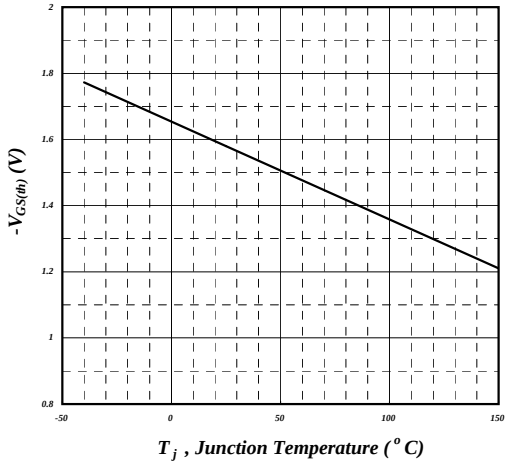


Fig 6. Gate Threshold Voltage v.s. Junction Temperature

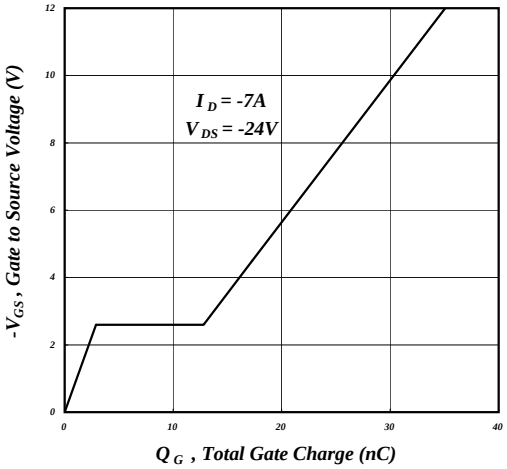


Fig 7. Gate Charge Characteristics

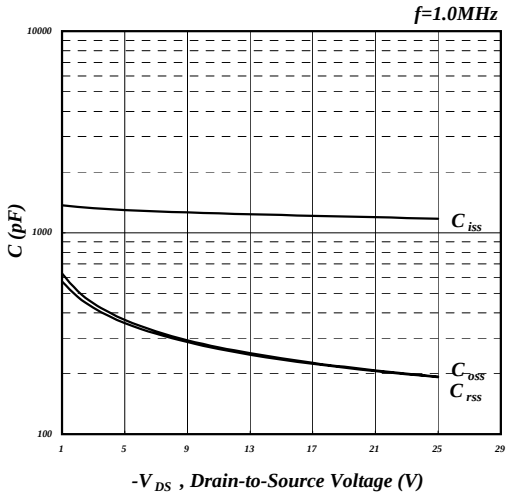


Fig 8. Typical Capacitance Characteristics

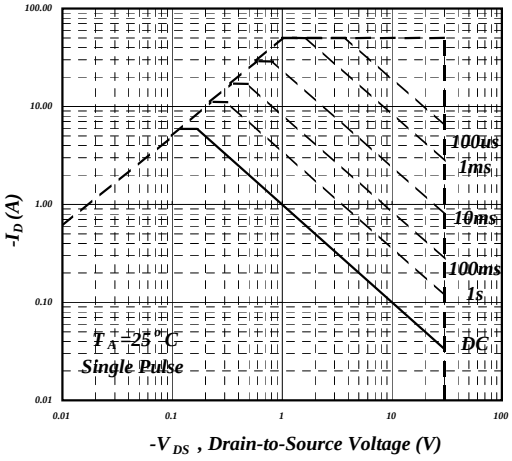


Fig 9. Maximum Safe Operating Area

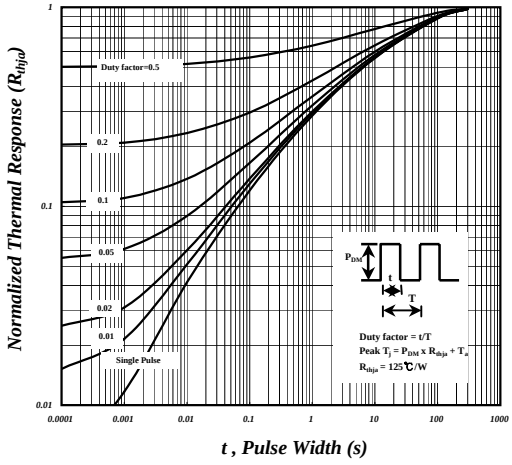


Fig 10. Effective Transient Thermal Impedance

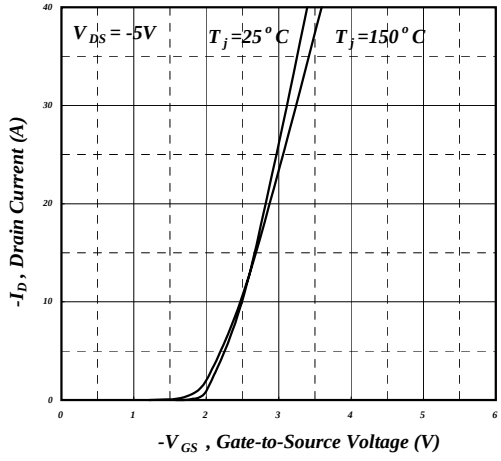


Fig 11. Transfer Characteristics

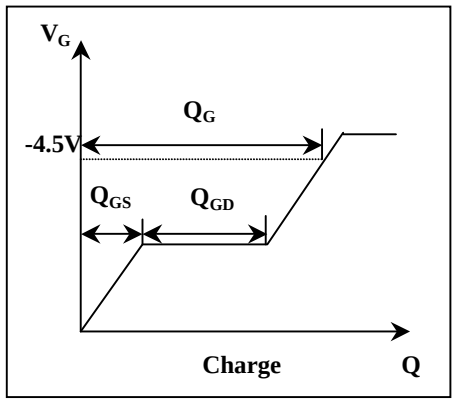
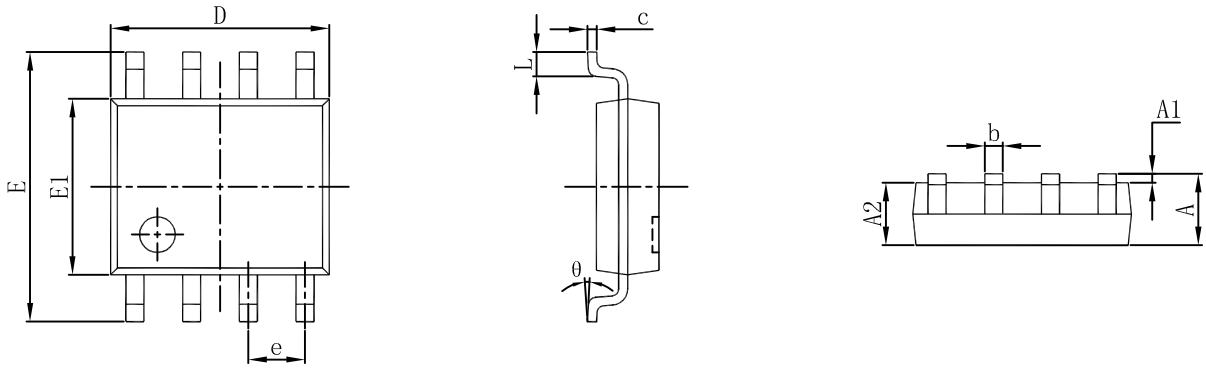
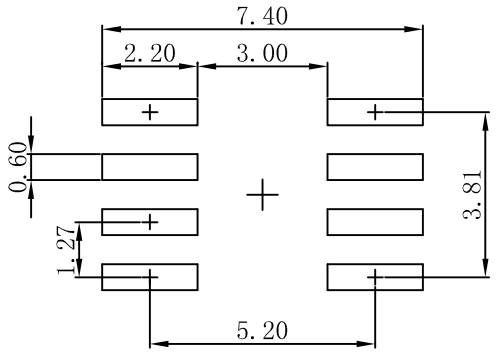


Fig 12. Gate Charge Circuit

SOP-8 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	**Max**	**Min**	**Max**
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.007	0.010
D	4.800	5.000	0.189	0.197
e	1.270 (BSC)		0.050 (BSC)	
E	5.800	6.200	0.228	0.244
E1	3.800	4.000	0.150	0.157
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°



Note:
1.Controlling dimension:in millimeters.
2.General tolerance:± 0.05mm.
3.The pad layout is for reference purposes only.

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